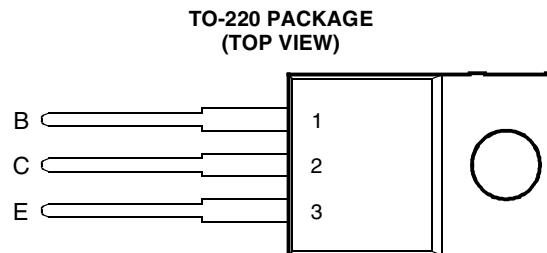


- Designed for Complementary Use with TIP120, TIP121 and TIP122
- 65 W at 25°C Case Temperature
- 5 A Continuous Collector Current
- Minimum h_{FE} of 1000 at 3 V, 3 A



Pin 2 is in electrical contact with the mounting base.

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absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ($I_E = 0$)	TIP125	V_{CBO}	-60	V
	TIP126		-80	
	TIP127		-100	
Collector-emitter voltage ($I_B = 0$)	TIP125	V_{CEO}	-60	V
	TIP126		-80	
	TIP127		-100	
Emitter-base voltage		V_{EBO}	-5	V
Continuous collector current		I_C	-5	A
Peak collector current (see Note 1)		I_{CM}	-8	A
Continuous base current		I_B	-0.1	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)		P_{tot}	65	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)		P_{tot}	2	W
Unclamped inductive load energy (see Note 4)		$\frac{1}{2}L_C^2$	50	mJ
Operating junction temperature range		T_j	-65 to +150	°C
Storage temperature range		T_{stg}	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds		T_L	260	°C

NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle $\leq 10\%$.

2. Derate linearly to 150°C case temperature at the rate of 0.52 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of: $L = 20$ mH, $I_{B(on)} = -5$ mA, $R_{BE} = 100$ Ω, $V_{BE(off)} = 0$, $R_S = 0.1$ Ω, $V_{CC} = -20$ V.

PRODUCT INFORMATION

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Specifications are subject to change without notice.

electrical characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$	Collector-emitter breakdown voltage Collector-emitter cut-off current	$I_C = -30 \text{ mA}$ $V_{CE} = -30 \text{ V}$ $V_{CE} = -40 \text{ V}$ $V_{CE} = -50 \text{ V}$	$I_B = 0$ $I_B = 0$ $I_B = 0$	TIP125 TIP126 TIP127	-60 -80 -100		V
I_{CEO}	Collector cut-off current	$V_{CB} = -60 \text{ V}$ $V_{CB} = -80 \text{ V}$ $V_{CB} = -100 \text{ V}$	$I_E = 0$ $I_E = 0$ $I_E = 0$	TIP125 TIP126 TIP127		-0.5 -0.5 -0.5	mA
I_{CBO}	Emitter cut-off current	$V_{EB} = -5 \text{ V}$	$I_C = 0$			-0.2 -0.2 -0.2	mA
h_{FE}	Forward current transfer ratio	$V_{CE} = -3 \text{ V}$ $V_{CE} = -3 \text{ V}$	$I_C = -0.5 \text{ A}$ $I_C = -3 \text{ A}$	(see Notes 5 and 6)	1000 1000		
$V_{CE(sat)}$	Collector-emitter saturation voltage	$I_B = -12 \text{ mA}$ $I_B = -20 \text{ mA}$	$I_C = -3 \text{ A}$ $I_C = -5 \text{ A}$	(see Notes 5 and 6)		-2 -4	V
V_{BE}	Base-emitter voltage	$V_{CE} = -3 \text{ V}$	$I_C = -3 \text{ A}$	(see Notes 5 and 6)		-2.5	V
V_{EC}	Parallel diode forward voltage	$I_E = -5 \text{ A}$	$I_B = 0$	(see Notes 5 and 6)		-3.5	V

NOTES: 5. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance			1.92	°C/W
$R_{\theta JA}$ Junction to free air thermal resistance			62.5	°C/W

resistive-load-switching characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS [†]			MIN	TYP	MAX	UNIT
t_{on} Turn-on time	$I_C = -3 \text{ A}$	$I_{B(on)} = -12 \text{ mA}$	$I_{B(off)} = 12 \text{ mA}$		1.5		μs
t_{off} Turn-off time	$V_{BE(off)} = 5 \text{ V}$	$R_L = 10 \Omega$	$t_p = 20 \mu\text{s}, dc \leq 2\%$		8.5		μs

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

PRODUCT INFORMATION

TYPICAL CHARACTERISTICS

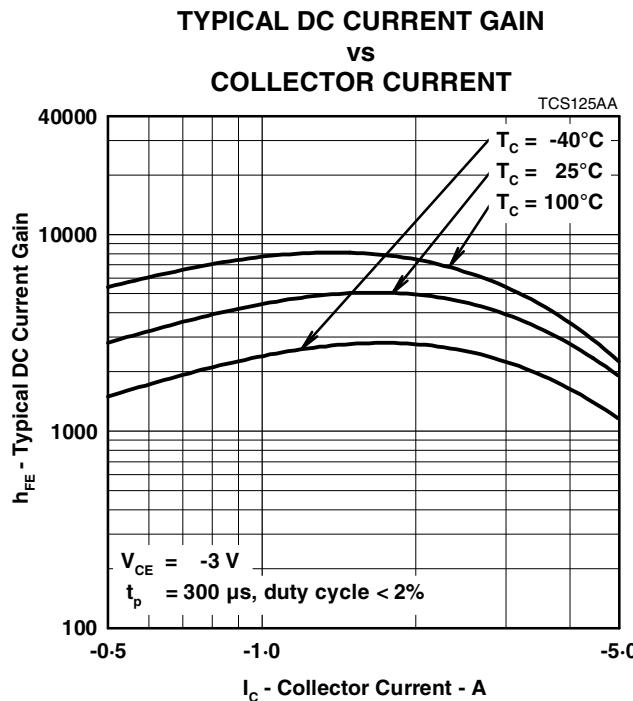


Figure 1.

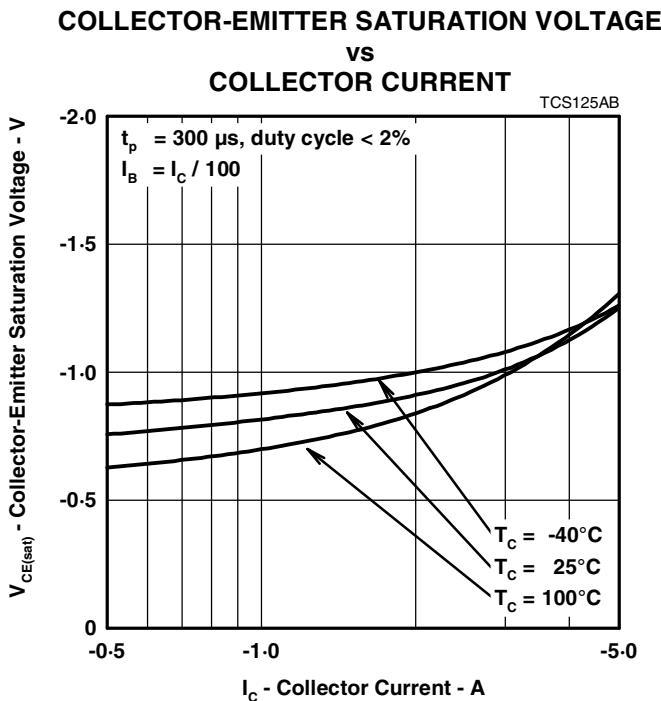


Figure 2.

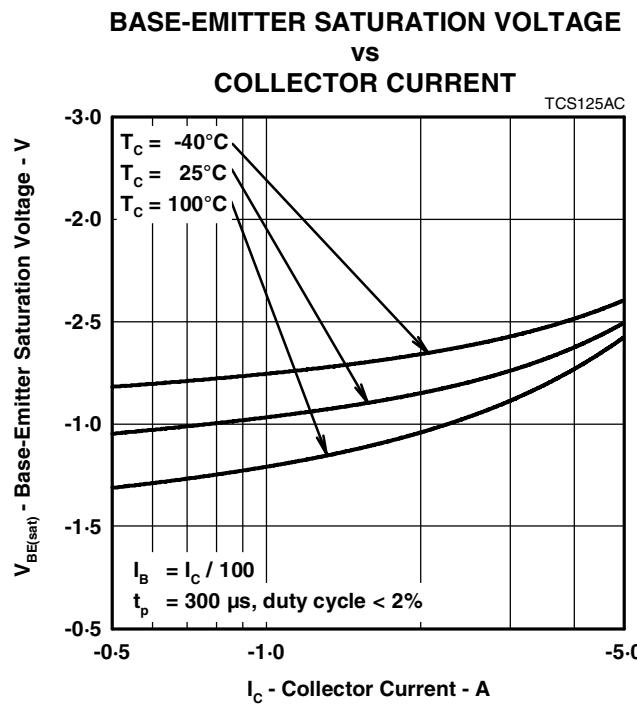


Figure 3.

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MAXIMUM SAFE OPERATING REGIONS

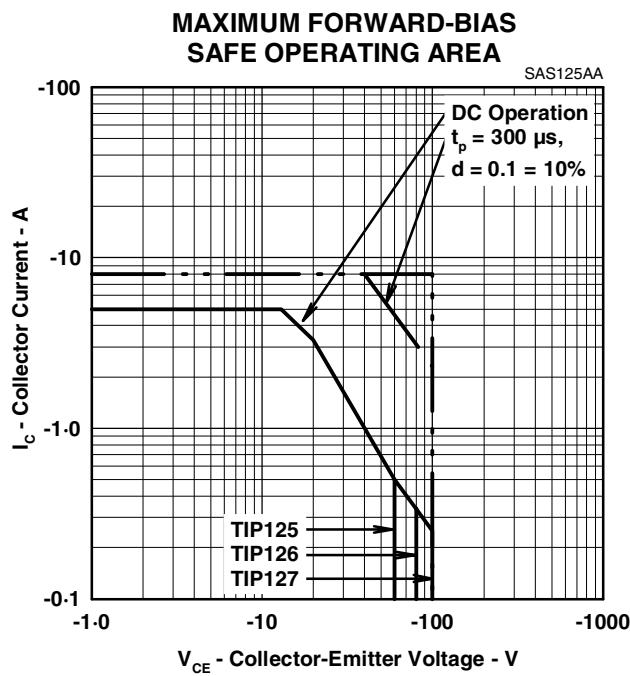


Figure 4.

THERMAL INFORMATION

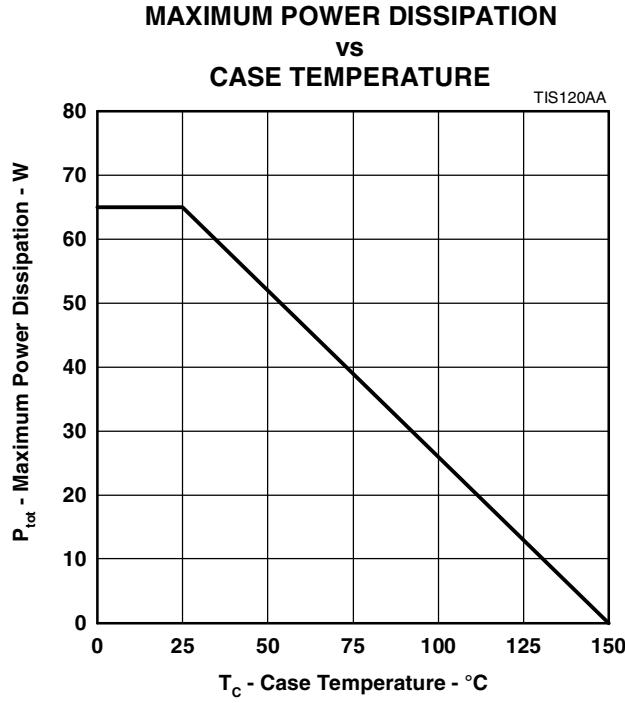


Figure 5.

PRODUCT INFORMATION